Roll No	•••••					Question Booklet Number
O. M. R. Serial No.						

M. Sc. (Electronics) (Fourth Semester) EXAMINATION, July, 2022

(Elective Course)

FOUNDATION OF NANO ELECTRONICS

P	ape	r Co	de	
ELC	4	0	4	(E)

Questions Booklet Series

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[Maximum Marks : 100

Time: 1:30 Hours]

Instructions to the Examinee:

- 1. Do not open the booklet unless you are asked to do so.
- 2. The booklet contains 60 questions. Examinee is required to answer any 50 questions in the OMR Answer-Sheet provided and not in the question booklet. If more than 50 questions are attempted by student, then the first attempted 50 questions will be considered for evaluation. All questions carry equal marks.
- 3. Examine the Booklet and the OMR Answer-Sheet very carefully before you proceed. Faulty question booklet due to missing or duplicate pages/questions or having any other discrepancy should be got immediately replaced.

परीक्षार्थियों के लिए निर्देश:

- प्रश्न-पुस्तिका को तब तक न खोलें जब तक आपसे कहा न जाए।
- 2. प्रश्न-पुस्तिका में 60 प्रश्न हैं। परीक्षार्थी को किन्हीं 50 प्रश्नों को केवल दी गई OMR आन्सर-शीट पर ही हल करना है, प्रश्न-पुस्तिका पर नहीं। यदि छात्र द्वारा 50 से अधिक प्रश्नों को हल किया जाता है तो प्रारम्भिक हल किये हुए 50 उत्तरों को ही मूल्यांकन हेतु सम्मिलित किया जाएगा। सभी प्रश्नों के अंक समान हैं।
- उत्तर अंकित करने से पूर्व प्रश्न-पुस्तिका तथा OMR आन्सर-शीट को सावधानीपूर्वक देख लें। दोषपूर्ण प्रश्न-पुस्तिका जिसमें कुछ भाग छपने से छूट गए हों या प्रश्न एक से अधिक बार छप गए हों या उसमें किसी अन्य प्रकार की कमी हो, तो उसे तुरन्त बदल लें।

(शेष निर्देश अन्तिम पृष्ठ पर)

(Only for Rough Work)

1.	The	depletion layer of tunnel diode is	5.	The p	phenomenon of scattering of light by
	very	small because		the co	olloidal particles is called
	(A)	its abrupt and has high dopants		(A)	Dispersion of light
	(B)	uses positive conductance property		(B)	Tyndall effect
	, ,			(C)	Atmospheric scattering
	(C)	its used for high frequency ranges		(D)	Atmospheric refraction
	(D)	tunneling effect	6.	Thor	e are three important lengths which
2.	Who	introduced 'First Vertical Power	0.		the theory of superconductivity,
	MOS	SFET'?		excep	ot:
	(A)	Mohammed Atalla		(A)	London penetration length
	(B)	Dawon Kahng		(B)	Intrinsic coherence length
	(C)	Hitachi		(C)	Normal electron mean free length
	(D)	Both (A) and (B)		(D)	Mean path length
	(2)	Dom (1) and (D)	7.	The	magnetic lines of force cannot
3.	Whic	ch type of a device is MOSFET?		penet	trate the body of a superconductor, a
	(A)	Current-controlled		phen	omenon is known as:
	(B)	Voltage-controlled		(A)	Isotopic effect
	(C)	Voltage-controlled current source		(B)	BCS theory
	(D)	Voltage-controlled voltage source		(C)	Meissner effect
				(D)	London theory
4.	Wha	t are the main terminals that carry	8.	Whic	ch of the following conductor has
	curre	ent?			est critical temperature ?
	(A)	Source		(A)	Aluminium
	(B)	Drain		(B)	Zinc
	(C)	Source and Drain		(C)	Molybdenum
	(D)	Gate		(D)	Tin

(3)

Set-C

9.	The different types of energies associated	12.	The transition zone for Raman spectra
	with a molecule are		is:
	(A) Electronic energy		(A) Between vibrational and rotational levels
	(B) Vibrational energy		(B) Between electronic levels
	(C) Rotational energy		(C) Between magnetic levels of nuclei
	(D) All of the above		(D) Between magnetic levels of unpaired electrons
10.	During the motion, if the centre of	13.	The criteria for electronic spin resonance
	gravity of molecule changes, the		is
	molecule possess		(A) Periodic change in polarisability
	morecule possess		(B) Spin quantum number of nuclei > 0
	(A) Electronic energy		(C) Presence of unpaired electron in a
	(B) Rotational energy		molecule
	(C) Translational energy		(D) Presence of chromophore in a molecule
	(D) Vibrational energy	14.	Brownian motion occurs in
11.	Which of the following is an application		(A) Inertial impaction
	of molecular spectroscopy?		(B) Diffusion
	(A) Structural investigation		(C) Electrostatic attraction(D) Interception
	(B) Basis of understanding of colors	15.	Phase space is a
	(C) Study of energetically excited		(A) 3-dimensional space
	reaction products		(B) 4-dimensional space
	-		(C) 5-dimensional space
	(D) All of the above		(D) 6-dimensional space

16.	Maxwell-Boltzmann's law is for	20.	Which of the following digital logic
	the		circuits can be used to add more than
	(A) Distinguishable particles		1-bit simultaneously ?
	(B) Indistinguishable particles		(A) Full-adder
	(C) Particles with half integral spin		(B) Ripple-carry adder
	(D) Particles with integral spin		(C) Half-adder
17.	The average kinetic energy associated		(D) Serial adder
	with each degree of freedom is	21.	When can one logic gate drive many
		21.	
	(A) kT		other logic gates in Digital Electronics?
	(B) 2 <i>k</i> T		(A) When its output impedance is low
	(C) $kT/2$		and the input impedance is low.
	(D) <i>k</i> T/4		(B) When its output impedance is high
18.	The density of molecules is maximum at		and the input impedance is high.
20.	which speed ?		(C) When its output impedance is high
	(A) V _{rms}		and the input impedance is low.
	(B) V_p		(D) When its output impedance is low
	(C) V _{mean}		and the input impedance is high.
	(D) V _{inst}	22.	What is a switching function that has
	This is		more than one output called in Digital
19.	Which gates in digital circuits are		-
	required to convert a NOR-based SR		Electronics ?
	latch to an SR flip- flop?		(A) Multi-gate function
	(A) Two 2 input AND gates		(B) Multi-output function
	(B) Two 3 input AND gates		(C) Multiple gate function
	(C) Two 2 input OR gates		(C) Multiple gate function
	(D) Two 3 input OR gates		(D) Multiple output function

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Set-C

	logic	e circuit ?		prov	ide
	(A)	Combinational logic circuits		(A)	small change in resistance
	(B)	Sequential logic circuits		(B)	no change in resistance
	(C)	Both (A) and (B)		(C)	large change in resistance
	(D)	None of the above		(D)	infinite change in resistance
24.		ch of the following is correct for tal Circuits? Less susceptible to noise or degradation in quality Use transistors to create logic gates to perform Boolean logic Easier to perform error detection and correction with digital signal	28.	appl (A) (B) (C) (D) Mos	it is available readily it is a noble metal it gives accurate measurements t metallic conductors have
25.	(D)	All of the above stance temperature detector		(A)	neutral temperature coefficient of resistance
23.				(B)	negative temperature coefficient of resistance
	(A) (B)	an electrical transducer a mechanical transducer		(C)	positive temperature coefficient of resistance
	(C) (D)	a chemical transducer a physical transducer		(D)	zero temperature coefficient of resistance
26.	Rela resis	tion between temperature and tance of a conductor is	30.		a temperature sensing
	(A)	$R_t = R_{\text{ref}}[1+t]$		(A)	low value of α is required
	(B)	$R_t = R_{\rm ref}[1 + \alpha \Delta t]$		(B)	infinite value of α is required
	(C)	$R_t = R_{\text{ref}}[1 - \alpha t]$		(C)	α must be zero
	(D)	$R_t = R_{\text{ref}}[1 - t]$		(D)	high value of α is required
ELC-	-404(E	E)	(6)		Set-C

Which of the follow is a type of digital 27. Sensing element in the thermometer must

23.

31.	Nanomaterials are the materials with at	35.	The first talk about Nanotechnology was
	least one dimension measuring less		given by:
	than		(A) Albert Einstein
	(A) 1 nm		(B) Newton
	(B) 10 nm		(C) Gordon E. Moore
	(C) 100 nm		
	(D) 1000 nm		(D) Richard Feynman
32.	A material with one dimension in Nano-	36.	Which of the processes of materials was
	range and the other two dimensions are		not described as Nanotechnology?
	large is called		(A) Separation
	(A) Micro-material		(B) Creation
	(B) Quantum wire		(C) Processing
	(C) Quantum well		- · ·
	(D) Quantum dot		(D) Consolidation
33.	The colour of the nanogold particles	37.	The initial tools used to help launch the
	is		nanoscience revolution were
	(A) Yellow		(A) Binoculars
	(B) Orange		(B) Microscope
	(C) Red		(C) Scanning probe instruments
	(D) Variable		(D) Interferometer
34.	The melting point of particles in nano-	20	The size of stome is nearly
	form	38.	The size of atoms is nearly
	(A) Increases		(A) 0.01 nm
	(B) Decreases		(B) 0.1 nm
	(C) Remains same		(C) 1 nm
	(D) Increases then decreases		(D) 10 nm

(7)

Set-C

39.	Nanosized polymers built from branched	43.	Vesicle is a type of
	units are called:		(A) nanostructure
	(A) dendrimers		(B) nanoparticle
	(B) composites		\
	(C) carbon-based materials		(C) nanocrystal
	(D) metal-based materials		(D) supramolecular system
40.	Which property of nanoparticles provides	44.	Specific heat of materials is expressed in
	a driving force for diffusion ?		
	(A) Optical properties		terms of:
	(B) High surface area to volume ratio		(A) W/m-K
	(C) Sintering		(b) J/k
	(D) There is no such property		(C) J/kg-K
41.	On both ends of the CNTs, which carbon		
	nanostructure is placed?		(D) m^3/kg
	(A) Graphite	45.	Which term is used to define the
	(B) Diamond		
	(C) C-60		temperature at which a substance
	(D) Benzene		changes its status from solid to liquid?
42.	Quantum dots can be used in		(A) Boiling point
	(A) crystallography		(B) Melting point
	(B) optoelectronics		(C) Condensation point
	(C) mechanics		•
	(D) quantum physics		(D) Freezing point

(8)

Set-C

46.	What is the procedure in top-down	50.	Who first produced nanostructured
	fabrication method ?		materials?
	(A) nanoparticles \rightarrow powder \rightarrow bulk		(A) Gerd Binning
	(B) powder \rightarrow bulk \rightarrow nanoparticles		(B) Alex Zettl
	(C) bulk \rightarrow powder \rightarrow nanoparticles		(C) P.M. Ajayan
	(D) nanoparticles \rightarrow bulk \rightarrow powder		(D) H. Gleiter
47.	What kind of metals are used for milling	51.	The range of magnetoelectrostatic force
	operations ?		in the air is around
	(A) Soft and brittle		(A) 10 mm
	(B) Soft and elastic		(B) 100 cm
	(C) Hard and brittle		(C) 100 nm
	(D) Hard and elastic		(D) None of the above
48.	CVD stands for:	52.	What is the standard form of TEM?
	(A) Carbon Vapour Density		(A) Transformer Element Microscopy
	(B) Chemical Vapour Density		(B) Transistor Electron Microscopy
	(C) Chemical Vapour Deposition		(C) Transmission Electron Microscopy
	(D) Carbon Vapour Deposition		(D) None of the above
49.	Ultrasonic machining process can be	53.	Which one of the following is a characterization technique in carbon
	used for:		nanotubes ?
	(A) Conductors		(A) TEM
	(B) Insulators		(B) SEM
	(C) Metals		(C) AFM
	(D) All of the above		(D) All of the above
ELC-	-404(E) (9)	Set-C

54.	Which one of the following nanosensors	58.	If 'X' corresponds to a tunnel diode and
	measures the flux density?		'Y' to an avalanche diode, then:
	(A) Mechanical		(A) X operates in reverse bias and Y
	(B) Thermal		operates in forward bias
	(C) Magnetic		(B) X operates in reverse bias and Y
	(D) Chemical		operates in reverse bias
55.	Which one of the following nanosensors		(C) X operates in forward bias and Y operates in forward bias
	measures the wavelength?		(D) X operates in forward bias and Y
	(A) Mechanical		operates in reverse bias
	(B) Thermal	59.	The range of tunnel diode voltage V_D ,
	(C) Magnetic		for which slope of its V-I characteristics
	(D) Optical		is negative would be (The V_P is the
56.	Which one of the following is an		peak voltage and V_V is the valley
	example of two-dimensional		voltage)
	nanostructure ?		$(A) V_D > 0$
	(A) Nanotubes		$(B) 0 < V_D < V_P$
	(B) Nanorods		$(C) V_{V} > V_{D} > V_{P}$
	(C) Nanolayers		(D) $V_D > V_V < V_P$
	(D) All of the above		(=) ,D
57.	What is the standard form of VLS ?	60.	Tunnel diode has a very fast operation in
	(A) Vacuum Liquid Solid		
	(B) Vapour Liquid Surface		(A) gamma frequency region
	(C) Vapour Liquid Solid		(B) ultraviolet frequency region
	(D) None of the above		(C) microwave frequency region
	(D) None of the above		(D) radio frequency region

(Only for Rough Work)

4. Four alternative answers are mentioned for each question as—A, B, C & D in the booklet. The candidate has to choose the most correct/appropriate answer and mark the same in the OMR Answer-Sheet as per the direction:

Example:

Question:

Q.1 (A) (C) (D)
Q.2 (A) (B) (C) (D)
Q.3 (A) (C) (D)

Illegible answers with cutting and over-writing or half filled circle will be cancelled.

- 5. Each question carries equal marks. Marks will be awarded according to the number of correct answers you have.
- 6. All answers are to be given on OMR Answer sheet only. Answers given anywhere other than the place specified in the answer sheet will not be considered valid.
- 7. Before writing anything on the OMR Answer Sheet, all the instructions given in it should be read carefully.
- 8. After the completion of the examination candidates should leave the examination hall only after providing their OMR Answer Sheet to the invigilator. Candidate can carry their Question Booklet.
- 9. There will be no negative marking.
- 10. Rough work, if any, should be done on the blank pages provided for the purpose in the booklet.
- 11. To bring and use of log-book, calculator, pager and cellular phone in examination hall is prohibited.
- 12. In case of any difference found in English and Hindi version of the question, the English version of the question will be held authentic.
- Impt.: On opening the question booklet, first check that all the pages of the question booklet are printed properly. If there is ny discrepancy in the question Booklet, then after showing it to the invigilator, get another question Booklet of the same series.

4. प्रश्न-पुस्तिका में प्रत्येक प्रश्न के चार सम्भावित उत्तर—
A, B, C एवं D हैं। परीक्षार्थी को उन चारों विकल्पों में से
एक सबसे सही अथवा सबसे उपयुक्त उत्तर छाँटना है।
उत्तर को OMR आन्सर-शीट में सम्बन्धित प्रश्न संख्या में
निम्न प्रकार भरना है:

उदाहरण :

प्रश्न :

प्रश्न 1 (A) (C) (D) प्रश्न 2 (A) (B) (D) प्रश्न 3 (A) (C) (D)

अपठनीय उत्तर या ऐसे उत्तर जिन्हें काटा या बदला गया है, या गोले में आधा भरकर दिया गया, उन्हें निरस्त कर दिया जाएगा।

- 5. प्रत्येक प्रश्न के अंक समान हैं। आपके जितने उत्तर सही होंगे, उन्हीं के अनुसार अंक प्रदान किये जायेंगे।
- 6. सभी उत्तर केवल ओ. एम. आर. उत्तर-पत्रक (OMR Answer Sheet) पर ही दिये जाने हैं। उत्तर-पत्रक में निर्धारित स्थान के अलावा अन्यत्र कहीं पर दिया गया उत्तर मान्य नहीं होगा।
- ओ. एम. आर. उत्तर-पत्रक (OMR Answer Sheet) पर कुछ भी लिखने से पूर्व उसमें दिये गये सभी अनुदेशों को सावधानीपूर्वक पढ़ लिया जाये।
- 8. परीक्षा समाप्ति के उपरान्त परीक्षार्थी कक्ष निरीक्षक को अपनी OMR Answer Sheet उपलब्ध कराने के बाद ही परीक्षा कक्ष से प्रस्थान करें। परीक्षार्थी अपने साथ प्रश्न-पुस्तिका ले जा सकते हैं।
- 9. निगेटिव मार्किंग नहीं है।
- 10. कोई भी रफ कार्य, प्रश्न-पुस्तिका के अन्त में, रफ-कार्य के लिए दिए खाली पेज पर ही किया जाना चाहिए।
- 11. परीक्षा-कक्ष में लॉग-बुक, कैलकुलेटर, पेजर तथा सेल्युलर फोन ले जाना तथा उसका उपयोग करना वर्जित है।
- 12. प्रश्न के हिन्दी एवं अंग्रेजी रूपान्तरण में भिन्नता होने की दशा में प्रश्न का अंग्रेजी रूपान्तरण ही मान्य होगा।

महत्वपूर्ण : प्रश्नपुस्तिका खोलने पर प्रथमतः जाँच कर देख लें कि प्रश्न-पुस्तिका के सभी पृष्ठ भलीभाँति छपे हुए हैं। यदि प्रश्नपुस्तिका में कोई कमी हो, तो कक्षनिरीक्षक को दिखाकर उसी सिरीज की दूसरी प्रश्न-पुस्तिका प्राप्त कर लें।